




SPECIFICATION SHEET

SPECIFICATION SHEET NO.	N1115 - DO218ABSM8S11A
DATE	Nov. 15, 2021
REVISION	A0
DESCRIPTION	SMD Transient Voltage Suppressor (TVS) Diodes, DO-218AB series, SM8S11A Type, 2 Pads, Uni-directional Stand-off Voltage 11V . Reverse Surge Current. 363A Max. Operating Temp. Range -55°C ~+175°C Package in Tape/Reel, 750pcs/13" Reel RoHS/RoHS III compliant
CUSTOMER	
CUSTOMER PART NUMBER	
CROSS REF. PART NUMBER	
ORIGINAL PART NUMBER	MDD SM8S11A
PART CODE	DO218ABSM8S11A

VENDOR APPROVE			
Issued/Checked/Approved			
DATE: Nov. 15, 2021			

CUSTOMER APPROVE	
DATE:	

SMD TRANSIENT VOLTAGE SUPPRESSORS DO-218AB SERIES



MAIN FEATURE

- Round Chip Produced By Chemical Method
- Junction Passivated By Polyimide
- T J – 175 °C Capability Suitable For High Reliability And Automotive Requirement
- Available In both Uni-directional and Bi-directional Polarity
- Low Leakage Current
- Low Forward Voltage Drop
- High Surge Capability
- Meet ISO7637-2 Surge Specification (Varied By Test Condition)
- Meet MSL Level 1, Per J-STD_020, LF Max. Peak Of 245 °C
- AEC – Q101 Quality

APPLICATION

- Use In Sensitive Electronics Protection Against Voltage Transients Included By Inductive Load Switching And Lighting, Especially For Automotive Load Dump Protection Application

RFQ

[Request For Quotation](#)

PART CODE GUIDE

DO218AB	SM8S11A
1	2

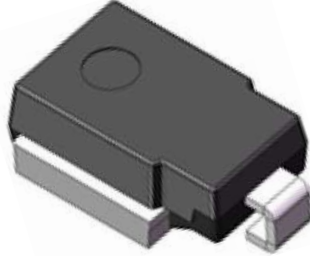
1) **DO218AB**: SMD Transient Voltage Suppressor (TVs) Diodes, DO218AB series

2) **SM8S11A**: Type code for original part number SM8S11A

SMD TRANSIENT VOLTAGE SUPPRESSORS DO-218AB SERIES

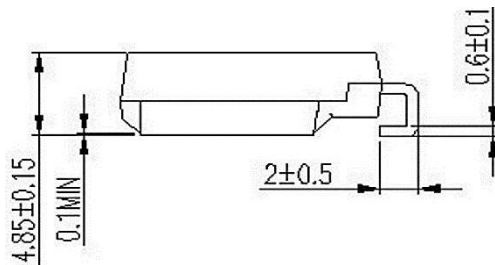
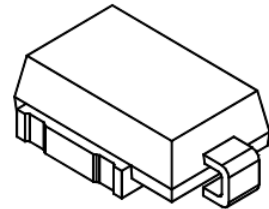
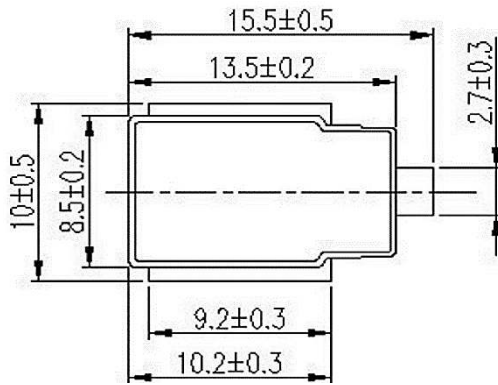
DIMENSION (Unit: mm)

Image for reference

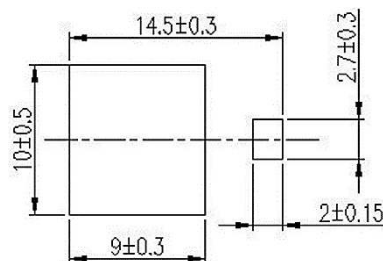


Marking: SM8S11A

DO-218AB



Recommend Pad Layout



SMD TRANSIENT VOLTAGE SUPPRESSORS DO-218AB SERIES
MECHANICAL DATA

Case	Terminals	Polarity	Mounting Position	Unit Weight
JEDEC DO-218AB molded plastic	Matte tin plated leads, solderable per J-STD-002 & JESD22-B102	Heatsink is Anode	Meets UL 94 V-0 flammability rating base P/NHE3_X – RoHS Compliant & AEC – Q101 qualified (X: denotes revision code e. g A, B...)	2.60 g/pc

MAX. RATING & CHARACTERISTICS - Ratings at 25°C ambient temperature unless otherwise specified.

Parameter	SYMBOLS	VALUE			UNITS
		Min.	Typical	Max.	
Peak Pulse Power Dissipation @10/1000µs Waveform	P _{ppm}		6600		W
Peak Pulse Power Dissipation @10/1000µs Waveform	P _{ppm}		5200		W
Power Dissipation On Infinite Heatsink @ T _c = 25 °C (Fig. 1)	P _D		8.0		W
Peak Pulse Current On 10/1000µs Waveform (Note 1)	I _{ppm}			363	A
Peak Forward Surge Current 8.3 Ms Single Half Sine- Wave	I _{FSM}		700		A
Thermal Resistance Junction To Case	R _{θJA}		0.90		°C/W
Operating Junction Temperature Range	T _J	-55		+175	°C
Storage Temperature Range	T _{STG}	-55		+175	°C

Note

1. Non-repetitive current pulse derated above TA=25 °C

SMD TRANSIENT VOLTAGE SUPPRESSORS DO-218AB SERIES

ELECTRICAL CHARACTERISTICS - Ratings at 25°C

Parameter	SYMBOLS	VALUE			UNITS
		Min.	Typical	Max.	
Breakdown Voltage	V _{BR}	12.2	12.9	13.5	V
Test Current	I _T		5.0		mA
Reverse Stand-Off	V _{WM}		11.0		V
Reverse Leakage @V _{WM}	I _D			10.0	μA
Reverse Leakage @ V _{WM} , T _J = 175 °C	I _D			150	μA
Peak Pulse Current @ 10/1000 μs Wave-form	I _{PPM}			363	A
Clamping Voltage @ I _{PPM}	V _C			18.2	V
Temp. Coefficient of V _{BR} (Note 1)	α _T		0.072		%/ °C

Note

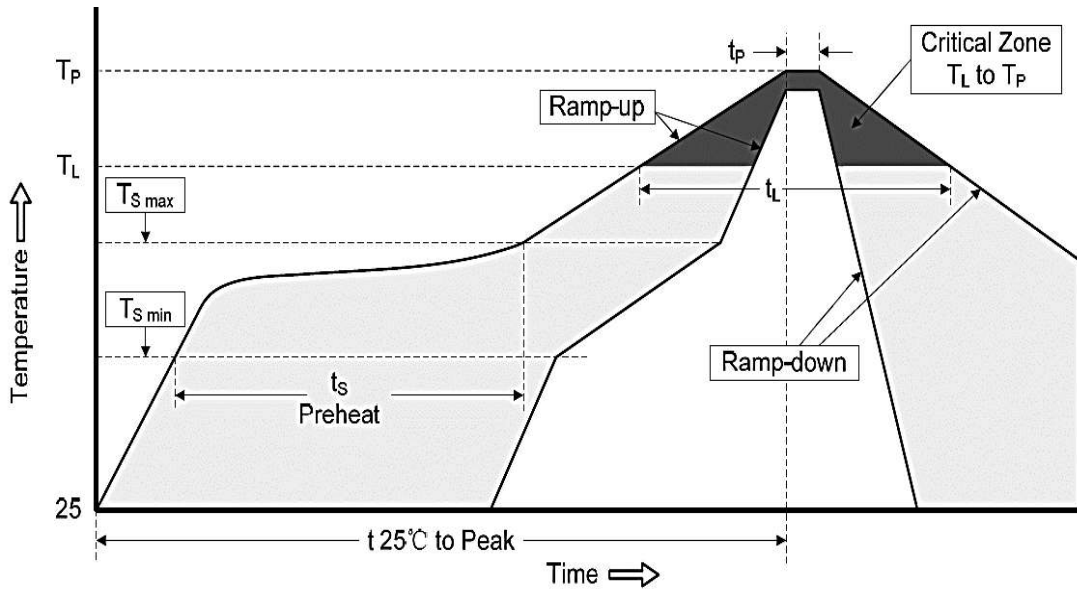
1. To calculate V_{BR} vs Junction temperature, use the following formula: V_{BR} at T_J = V_{BR} at 25 °C x 1+ α_T x (T_J -25)
2. For all type Max. V_F = 1.8V at I_F = 100 A measured on 8.3ms single half Sine-wave or equivalent square wave, duty cycle = 4 pulses per minute Max.

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RELIABILITY

Number	Experiment Items	Experiment Method And Conditions	Reference Documents
1	Solder Resistance Test	Test 260°C± 5°C for 10 ± 2 sec. Immerse body into solder 1/16" ± 1/32"	MIL-STD-750D METHOD-2031.2
2	Solderability Test	230°C ±5°C for 5 sec.	MIL-STD-750D METHOD-2026.1 0
3	Pull Test	1 kg in axial lead direction for 10 sec.	MIL-STD-750D METHOD-2036.4
4	Bend Test	0.5Kg Weight Applied To Each Lead, Bending Arcs 90 °C ± 5 °C For 3 Times	MIL-STD-750D METHOD-2036.4
5	High Temperature Reverse Bias Test	TA=100°C for 1000 Hours at VR=80% Rated VR	MIL-STD-750D METHOD-1038.4
6	Forward Operation Life Test	TA=25°C Rated Average Rectified Current	MIL-STD-750D METHOD-1027.3
7	Intermittent Operation Life Test	On state: 5 min with rated IRMS Power Off state: 5 min with Cool Forced Air. On and off for 1000 cycles.	MIL-STD-750D METHOD-1036.3
8	Pressure Cooker Test	15 PSIG, TA=121°C, 4 hours	MIL-S-19500 APPENOIXC
9	Temperature Cycling Test	-55°C~+125°C; 30 Minutes For Dwelled Time 5 minutes for transferred time. Total: 10 cycles.	MIL-STD-750D METHOD-1051.7
10	Thermal Shock Test	0°C for 5 minutes., 100°C for 5minutes, Total: 10 cycles	MIL-STD-750D METHOD-1056.7
11	Forward Surge Test	8.3ms Single Sale Sine-wave One Surge.	MIL-STD-750D METHOD-4066.4
12	Humidity Test	TA=65°C, RH=98% for 1000 hours.	MIL-STD-750D METHOD-1021.3
13	High Temperature Storage life Test	150°C for 1000 Hours	MIL-STD-750D METHOD-1031.5

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SUGGESTED REFLOW PROFILE (For Reference Only)



Profile Feature		Pb-Free Assembly
Average Ramp-up Rate (Ts Max to Tp)		3°C/second Max
Preheat	Temperature Min (Ts Min.)	150°C
	Temperature Max (Ts Max.)	200°C
	Time (ts Min. to ts Max.)	60 ~ 180 seconds
Time maintained above	Temperature (Tl)	217°C
	Time (tL)	60 ~ 150 seconds
Peak/Classification Temperature (Tp)		260 °C
Time within 5°C of actual Peak Temperature (tp)		20 ~ 40 seconds
Ramp-down rate		6 °C /Second Max.
Time 25 °C to Peak Temperature		6 minutes Max.
Suggest reflow times		3 Times Max.

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RATINGS AND CHARACTERISTIC CURVES (For Reference Only)

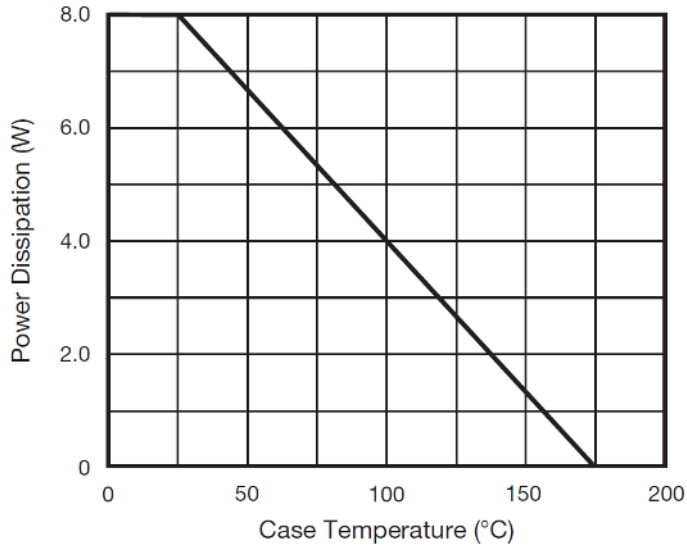


Fig. 1 - Power Derating Curve

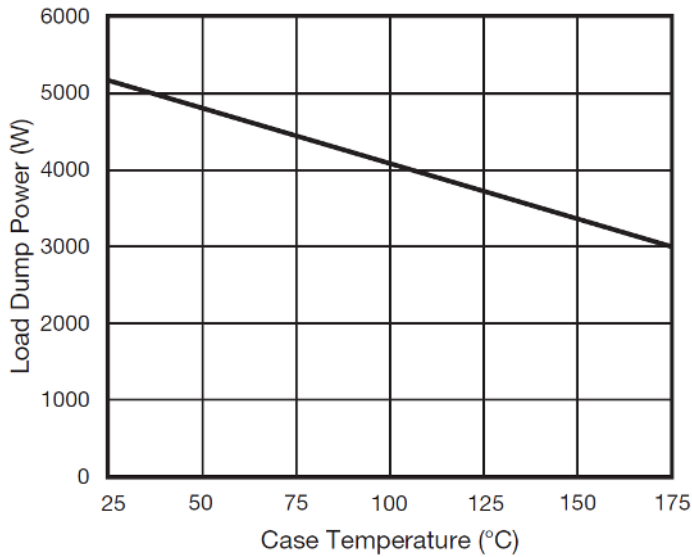


Fig. 2 - Load Dump Power Characteristics (10 ms Exponential Waveform)

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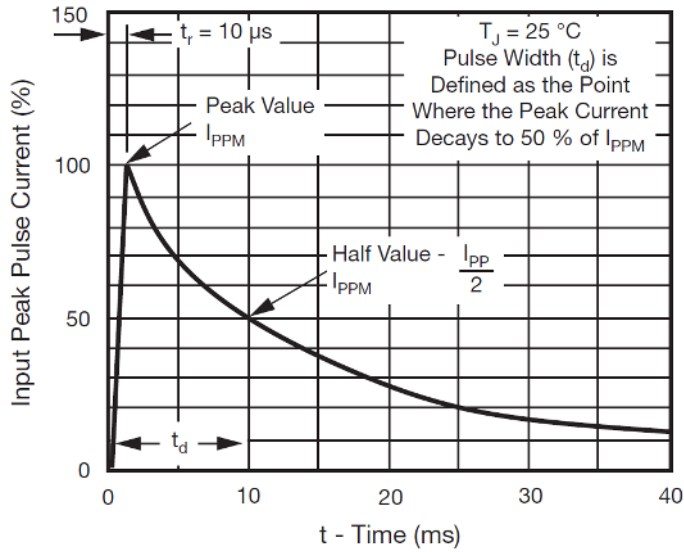


Fig. 3 - Pulse Waveform

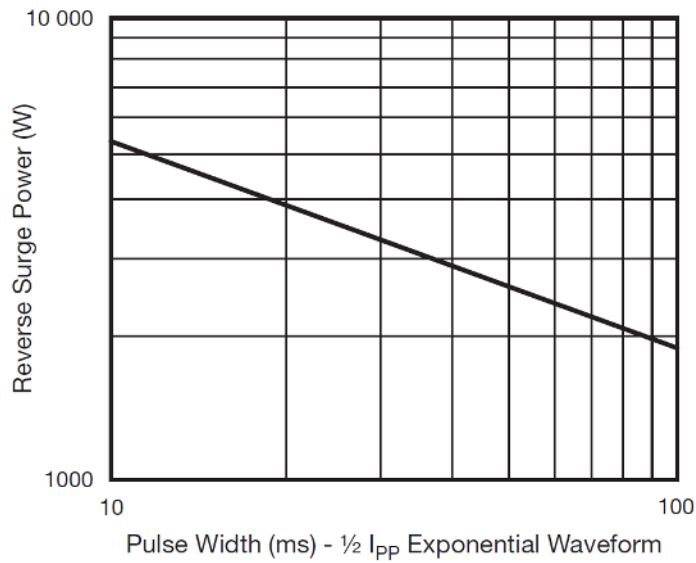


Fig. 4 - Reverse Power Capability

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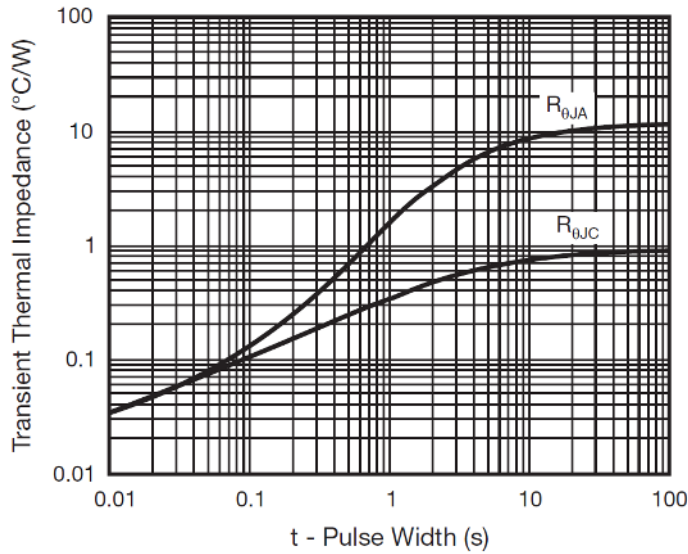


Fig. 5 - Typical Transient Thermal Impedance



Fig. 6 - Typical Junction Capacitance

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TAPE/REEL (Unit: mm)

All Devices are packed in accordance with EIA standard RS-481-A and specifications. 750pcs/Reel



Item	Symbol	Tolerance	DO-218AB
Carrier width	A	+/-0.30	10.80
Carrier Length	B	+/-0.30	16.13
Carrier Depth	C	+/-0.20	6.00
Sprocket hole	d	+/-0.20	1.55
13"Reel outside diameter	D	+/-0.30	330.00
13"Reel inner diameter	D1	-	50.0 Min.
Feed hole diameter	D2	-	20.2 Min.
Sprocket hole position	E	+/-0.2	1.75
Punch hole position	F	+/-0.20	11.50
Punch hole pitch	P	+/-0.20	16.0
Sprocket hole pitch	P0	+/-0.20	4.00
Embossment center	P1	+/-0.20	2.00
Overall tape thickness	T	-	-
Tape width	W	+/-0.20	24.00
Reel width	W1	-	30.40 Max.

SMD TRANSIENT VOLTAGE SUPPRESSORS DO-218AB SERIES

PACKAGE for reference

Case Code	DO- 218AB
Reel Size	13"
Reel Size	330 mm
MPQ/Reel	750 pcs
Qty. /Box	1500 pcs
G.W/Box	5.5 kgs

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